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BPV11F

Vishay Semiconductors

Silicon NPN Phototransistor

FEATURES

- Package type: leaded
- Package form: T-1¾
- Dimensions (in mm): Ø 5
- High radiant sensitivity
- Daylight blocking filter matched with 940 nm emitters
- Fast response times
- Angle of half sensitivity: $\varphi = \pm 15^{\circ}$
- Base terminal connected
- Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>

APPLICATIONS

• Detector for industrial electronic circuitry, measurement and control

PRODUCT SUMMARY				
COMPONENT	I _{ca} (mA)	φ (deg)	λ _{0.5} (nm)	
BPV11F	9	± 15	900 to 980	

Note

• Test condition see table "Basic Characteristics"

ORDERING INFORMATION				
ORDERING CODE	PACKAGING	REMARKS	PACKAGE FORM	
BPV11F	Bulk	MOQ: 4000 pcs, 4000 pcs/bulk	T-1¾	

Note

• MOQ: minimum order quantity

ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
Collector base voltage		V _{CBO}	80	V	
Collector emitter voltage		V _{CEO}	70	V	
Emitter base voltage		V _{EBO}	5	V	
Collector current		Ι _C	50	mA	
Collector peak current	t_p/T = 0.5, $t_p \le 10 \text{ ms}$	I _{CM}	100	mA	
Power dissipation	$T_{amb} \le 47 \ ^{\circ}C$	Pv	150	mW	
Junction temperature		Тj	100	°C	
Operating temperature range		T _{amb}	- 40 to + 100	°C	
Storage temperature range		T _{stg}	- 40 to + 100	°C	
Soldering temperature	$t \le 5$ s, 2 mm from body	T _{sd}	260	°C	
Thermal resistance junction/ambient	Connected with Cu wire, 0.14 mm ²	R _{thJA} 350		K/W	



www.vishay.com



BPV11F is a silicon NPN phototransistor with high radiant sensitivity in black, T-1³/₄ plastic package with base terminal and daylight blocking filter. Filter bandwidth is matched with 900 nm to 950 nm IR emitters.

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COMPLIANT



Vishay Semiconductors

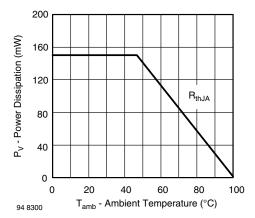


Fig. 1 - Power Dissipation Limit vs. Ambient Temperature

BASIC CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Collector emitter breakdown voltage	I _C = 1 mA	V _{(BR)CEO}	70			V
Collector emitter dark current	V _{CE} = 10 V, E = 0	I _{CEO}		1	50	nA
DC current gain	$V_{CE} = 5 \text{ V}, \text{ I}_{C} = 5 \text{ mA}, \text{ E} = 0$	h _{FE}		450		
Collector emitter capacitance	$V_{CE} = 0 V, f = 1 MHz, E = 0$	C _{CEO}		15		pF
Collector base capacitance	$V_{CE} = 0 V, f = 1 MHz, E = 0$	C _{CBO}		19		pF
Collector light current	$E_e=1$ mW/cm^2, $\lambda=950$ nm, $V_{CB}=5$ V	I _{ca}	3	9		mA
Angle of half sensitivity		φ		± 15		deg
Wavelength of peak sensitivity		λ _p		930		nm
Range of spectral bandwidth		λ _{0.5}		900 to 980		nm
Collector emitter saturation voltage	$E_e = 1 \text{ mW/cm}^2$, $\lambda = 950 \text{ nm}$, $I_C = 1 \text{ mA}$	V _{CEsat}		130	300	mV
Turn-on time	V_{S} = 5 V, I_{C} = 5 mA, R_{L} = 100 Ω	t _{on}		6		μs
Turn-off time	V_{S} = 5 V, I_{C} = 5 mA, R_{L} = 100 Ω	t _{off}		5		μs
Cut-off frequency	V_{S} = 5 V, I _C = 5 mA, R _L = 100 Ω	f _c		110		kHz

BASIC CHARACTERISTICS (Tamb = 25 °C, unless otherwise specified)

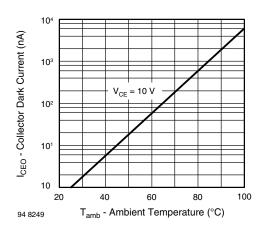


Fig. 2 - Collector Dark Current vs. Ambient Temperature

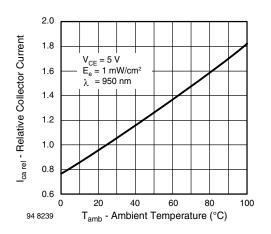
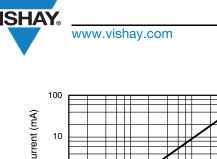


Fig. 3 - Relative Collector Current vs. Ambient Temperature

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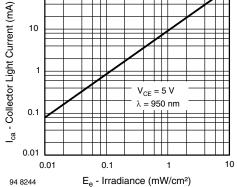


Fig. 4 - Collector Light Current vs. Irradiance

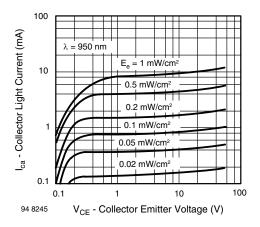


Fig. 5 - Collector Light Current vs. Collector Emitter Voltage

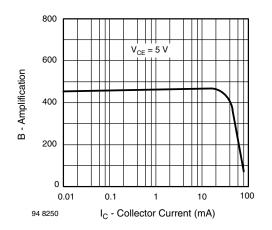


Fig. 6 - Amplification vs. Collector Current

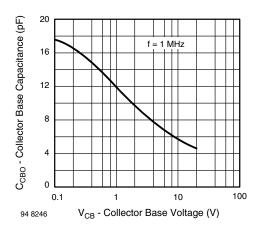


Fig. 7 - Collector Base Capacitance vs. Collector Base Voltage

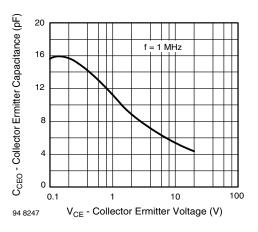


Fig. 8 - Collector Emitter Capacitance vs. Collector Emitter Voltage

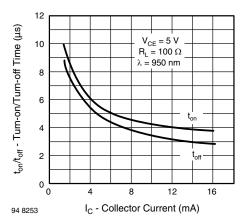
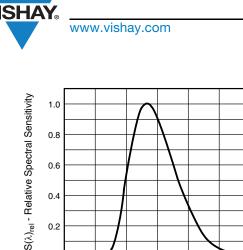


Fig. 9 - Turn-on/Turn-off Time vs. Collector Current

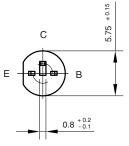
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0.2 0 800 900 1000 1100 94 8258 λ - Wavelength (nm)

Fig. 10 - Relative Spectral Sensitivity vs. Wavelength

PACKAGE DIMENSIONS in millimeters



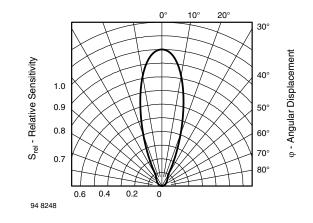
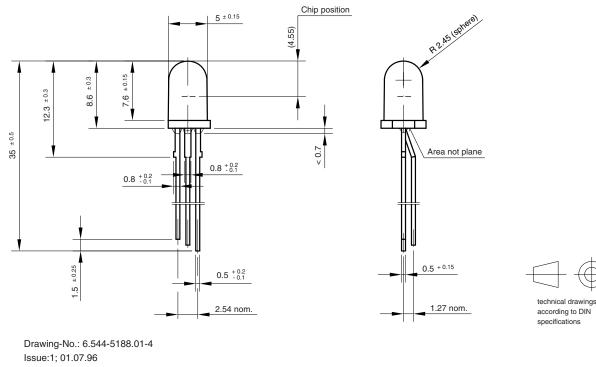


Fig. 11 - Relative Radiant Sensitivity vs. Angular Displacement



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